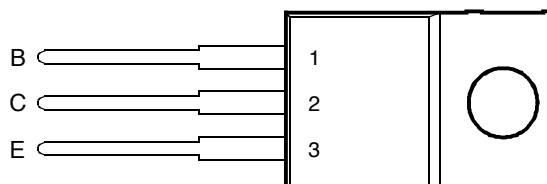


- Rugged Triple-Diffused Planar Construction
- 100 W at 25°C Case Temperature
- 5 A Continuous Collector Current



This series is `Sd` J_M/R_U
not recommended for new designs.

TO-220 PACKAGE
(TOP VIEW)



Pin 2 is in electrical contact with the mounting base.

MDTRACA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	SYMBOL	VALUE	UNIT
Collector-base voltage ($I_E = 0$)	V_{CBO}	850	V
Collector-emitter voltage ($V_{BE} = 0$)	V_{CES}	850	V
Collector-emitter voltage ($I_B = 0$)	V_{CEO}	400	V
Emitter-base voltage	V_{EBO}	10	V
Continuous collector current	I_C	5	A
Peak collector current (see Note 1)	I_{CM}	10	A
Continuous device dissipation at (or below) 25°C case temperature	P_{tot}	100	W
Operating junction temperature range	T_j	-65 to +150	°C
Storage temperature range	T_{stg}	-65 to +150	°C

NOTE 1: This value applies for $t_p \leq 10$ ms, duty cycle $\leq 2\%$.

PRODUCT INFORMATION

MAY 1989 - REVISED SEPTEMBER 2002
Specifications are subject to change without notice.

electrical characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
$V_{CEO(sus)}$	Collector-emitter sustaining voltage $I_C = 0.1 \text{ A}$	$L = 25 \text{ mH}$	(see Note 2)	400			V
I_{CES}	Collector-emitter cut-off current $V_{CE} = 850 \text{ V}$	$V_{BE} = 0$			50	500	μA
I_{EBO}	Emitter cut-off current $V_{EB} = 10 \text{ V}$	$I_C = 0$			1		mA
h_{FE}	Forward current transfer ratio $V_{CE} = 5 \text{ V}$	$I_C = 0.5 \text{ A}$	(see Notes 3 and 4)	20		60	
$V_{CE(sat)}$	Collector-emitter saturation voltage $I_B = 0.6 \text{ A}$	$I_C = 3 \text{ A}$	(see Notes 3 and 4)			1.5	V
$V_{BE(sat)}$	Base-emitter saturation voltage $I_B = 0.6 \text{ A}$	$I_C = 3 \text{ A}$	(see Notes 3 and 4)			1.3	V
f_t	Current gain bandwidth product $V_{CE} = 10 \text{ V}$	$I_C = 0.5 \text{ A}$	$f = 1 \text{ MHz}$		12		MHz
C_{ob}	Output capacitance $V_{CB} = 20 \text{ V}$	$I_E = 0$	$f = 0.1 \text{ MHz}$		110		pF

NOTES: 2. Inductive loop switching measurement.

3. These parameters must be measured using pulse techniques, $t_p = 300 \mu\text{s}$, duty cycle $\leq 2\%$.

4. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

thermal characteristics

PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$ Junction to case thermal resistance Junction to case thermal resistance			1.25	°C/W

inductive-load-switching characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS [†]			MIN	TYP	MAX	UNIT
t_{sv}	Voltage storage time $I_C = 3 \text{ A}$	$I_{B(on)} = 0.6 \text{ A}$	$V_{BE(off)} = -5 \text{ V}$			1.4	μs
t_{fi}	Current fall time $V_{CC} = 50 \text{ V}$	(see Figures 1 and 2)				150	ns
t_{sv}	Voltage storage time $I_C = 3 \text{ A}$	$I_{B(on)} = 0.6 \text{ A}$	$V_{BE(off)} = -5 \text{ V}$			1.5	μs
t_{fi}	Current fall time $V_{CC} = 50 \text{ V}$	$T_C = 100^\circ\text{C}$				300	ns

[†] Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

PRODUCT INFORMATION

PARAMETER MEASUREMENT INFORMATION

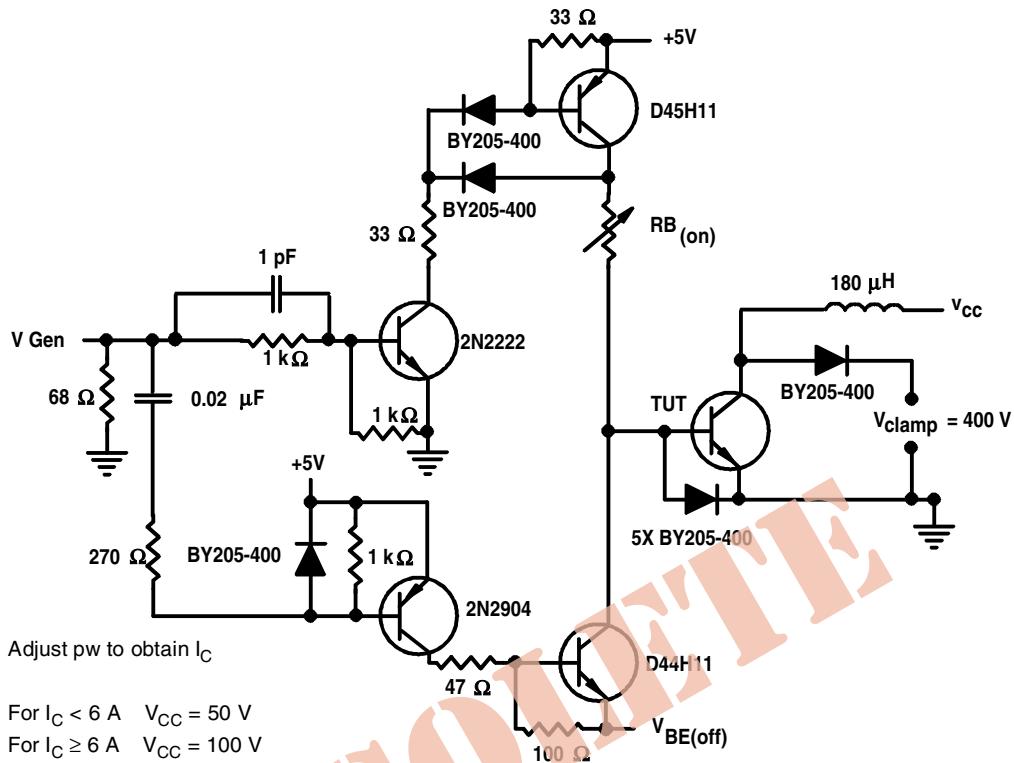
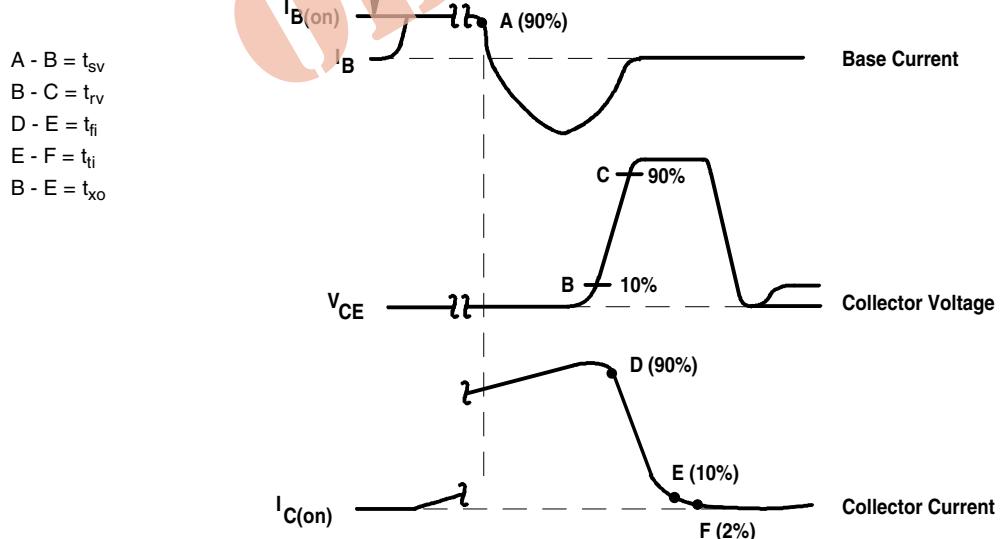


Figure 1. Inductive-Load Switching Test Circuit



NOTES: A. Waveforms are monitored on an oscilloscope with the following characteristics: $t_r < 15$ ns, $R_{in} > 10 \Omega$, $C_{in} < 11.5$ pF.
B. Resistors must be noninductive types.

Figure 2. Inductive-Load Switching Waveforms

PRODUCT INFORMATION

MAXIMUM SAFE OPERATING REGIONS

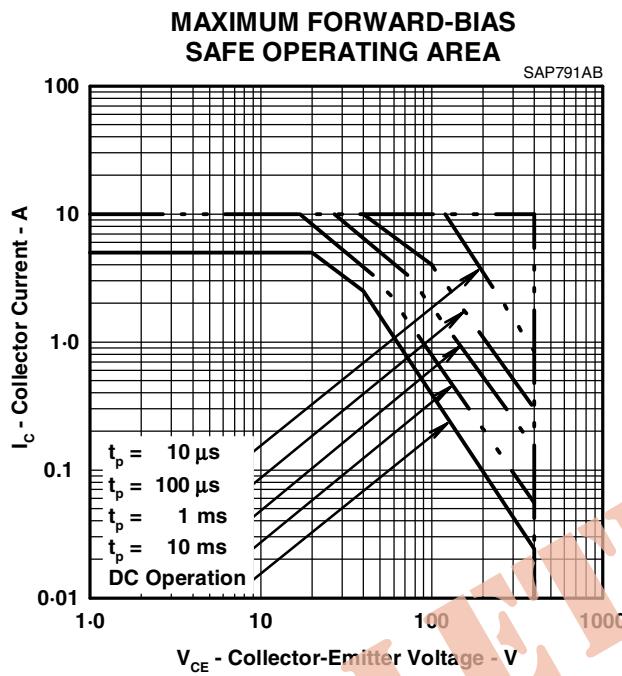


Figure 3.

PRODUCT INFORMATION